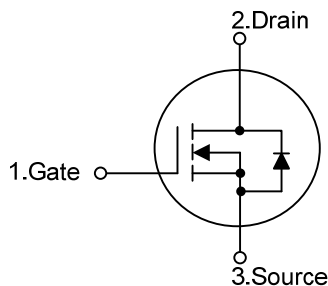


**15NM60****Power MOSFET****15A, 600V N-CHANNEL
SUPER-JUNCTION MOSFET****DESCRIPTION**

The UTC 15NM60 is a Super Junction MOSFET Structure and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and a high rugged avalanche characteristics. This power MOSFET is usually used at AC-DC converters for power applications.

FEATURES

- * $R_{DS(ON)} \leq 0.35 \Omega$ @ $V_{GS}=10V$, $I_D=7.5A$
- * By using Super Junction Structure
- * Fast Switching
- * With 100% Avalanche Tested

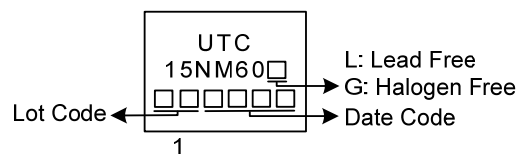
SYMBOL**ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
15NM60L-TA3-T	15NM60G-TA3-T	TO-220	G	D	S	Tube
15NM60L-TF1-T	15NM60G-TF1-T	TO-220F1	G	D	S	Tube
15NM60L-TF2-T	15NM60G-TF2-T	TO-220F2	G	D	S	Tube
15NM60L-TF3-T	15NM60G-TF3-T	TO-220F	G	D	S	Tube
15NM60L-TM3-T	15NM60G-TM3-T	TO-251	G	D	S	Tube
15NM60L-TN3-R	15NM60G-TN3-R	TO-252	G	D	S	Tape Reel
15NM60L-TW1-T	15NM60G-TW1-T	TO-220WF	G	D	S	Tube
15NM60L-TQ2-T	15NM60G-TQ2-T	TO-263	G	D	S	Tube
15NM60L-TQ2-R	15NM60G-TQ2-R	TO-263	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

15NM60G-TA3-T (1) Packing Type (2) Package Type (3) Green Package	(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2, TF3: TO-220F, TM3: TO-251, TN3: TO-252, TW1: TO-220WF, TQ2: TO-263 (3) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



■ **ABSOLUTE MAXIMUM RATINGS** ($T_c = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	600	V
Gate-Source Voltage		V_{GSS}	± 30	V
Drain Current	Continuous	I_D	15	A
	Pulsed (Note 2)	I_{DM}	45	A
Avalanche Current (Note 2)		I_{AR}	2.9	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	560	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	20	V/ns
Power Dissipation	TO-220/TO-263	P_D	83	W
	TO-220F/TO-220F1 TO-220F2/TO-220WF		31	W
	TO-251/TO-252		62	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature Range		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

3. $L=133\text{mH}$, $I_{AS}=2.9\text{A}$, $V_{DD}=50\text{V}$, $R_G=25\Omega$, Starting $T_J=25^\circ\text{C}$

4. $I_{SD} \leq 15\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J=25^\circ\text{C}$

■ **THERMAL DATA**

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F TO-220F1/TO-220F2 TO-220WF/TO-263	θ_{JA}	62.5	$^\circ\text{C}/\text{W}$
	TO-251/TO-252		110	$^\circ\text{C}/\text{W}$
	TO-220/TO-263		1.5	$^\circ\text{C}/\text{W}$
	TO-220F/TO-220F1 TO-220F2/TO-220WF		4	$^\circ\text{C}/\text{W}$
Junction to Case	TO-220/TO-263	θ_{JC}	1.5	$^\circ\text{C}/\text{W}$
	TO-220F/TO-220F1 TO-220F2/TO-220WF		4	$^\circ\text{C}/\text{W}$
	TO-251/TO-252		2.02 (Note)	$^\circ\text{C}/\text{W}$

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

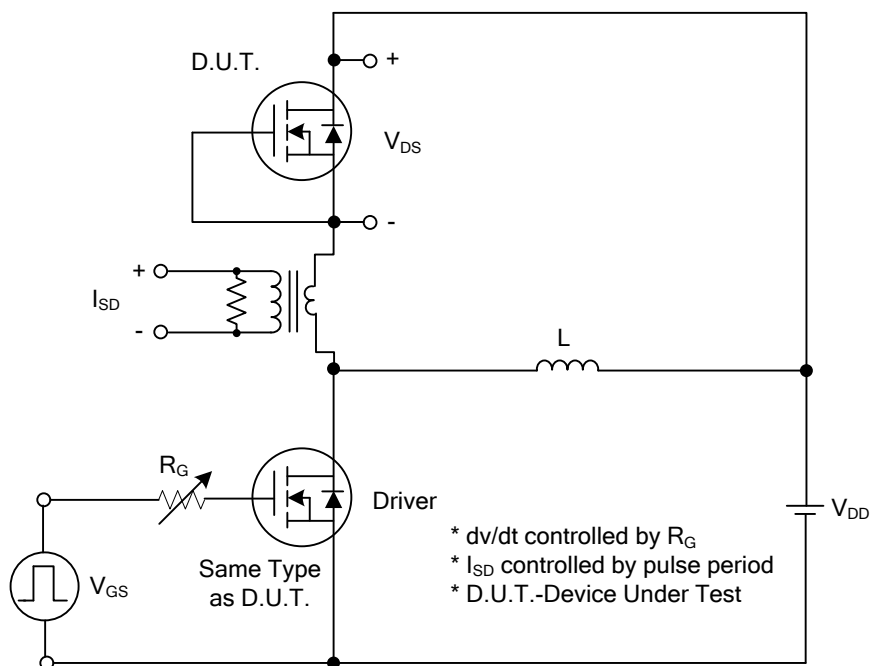
■ **ELECTRICAL CHARACTERISTICS** ($T_J = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250μA	600			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} =600V, V _{GS} =0V			10	μA
Gate-Source Leakage Current	Forward	I _{GSS}	V _{DS} =0V ,V _{GS} =30V			100	nA
	Reverse		V _{DS} =0V ,V _{GS} =-30V			-100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} = V _{GS} , I _D =250μA	2.5		4.5	V
Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =7.5A			0.35	Ω
DYNAMIC PARAMETERS							
Input Capacitance		C _{ISS}	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		1140		pF
Output Capacitance		C _{OSS}			746		pF
Reverse Transfer Capacitance		C _{RSS}			50		pF
SWITCHING PARAMETERS							
Total Gate Charge (Note 1)		Q _G	V _{DS} =480V, V _{GS} =10V, I _D =15A , I _G =1mA (Note 1, 2)		51.2		nC
Gate to Source Charge		Q _{GS}			7.6		nC
Gate to Drain Charge		Q _{GD}			14		nC
Turn-ON Delay Time (Note 1)		t _{D(ON)}	V _{DD} =100V, V _{GS} =10V, I _D =15A, R _G =25Ω (Note 1, 2)		20		ns
Rise Time		t _R			22		ns
Turn-OFF Delay Time		t _{D(OFF)}			130		ns
Fall-Time		t _F			39		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Maximum Body-Diode Continuous Current		I _S				15	A
Maximum Body-Diode Pulsed Current		I _{SM}				45	A
Drain-Source Diode Forward Voltage (Note 1)		V _{SD}	I _S =15A, V _{GS} =0V			1.4	V
Body Diode Reverse Recovery Time (Note 1)		t _{rr}	I _S =15A, V _{GS} =0V,		400		nS
Body Diode Reverse Recovery Charge		Q _{rr}	dl _F /dt=100A/μs		6.51		μC

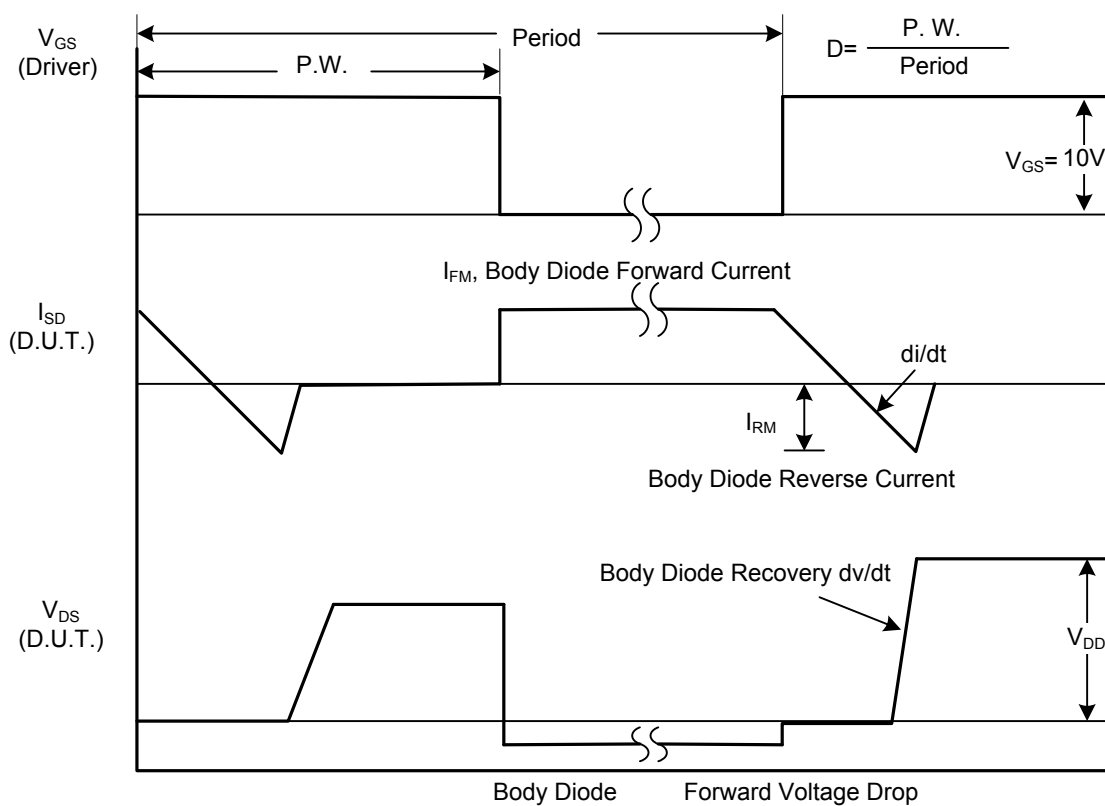
Notes: 1. Pulse Test : Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

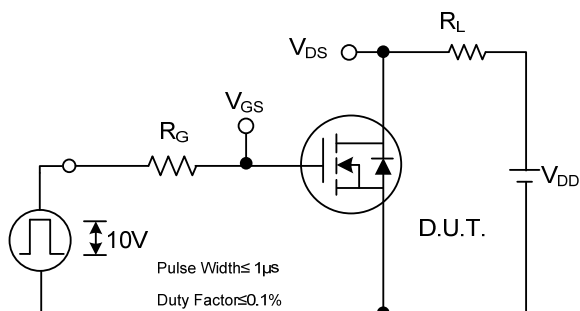


Peak Diode Recovery dv/dt Test Circuit

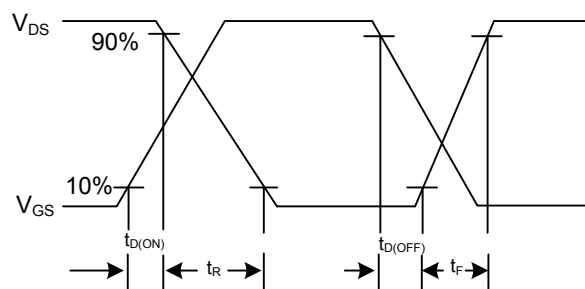


Peak Diode Recovery dv/dt Waveforms

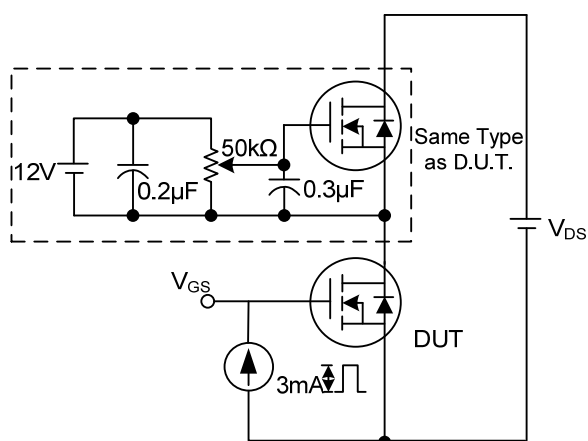
■ TEST CIRCUITS AND WAVEFORMS



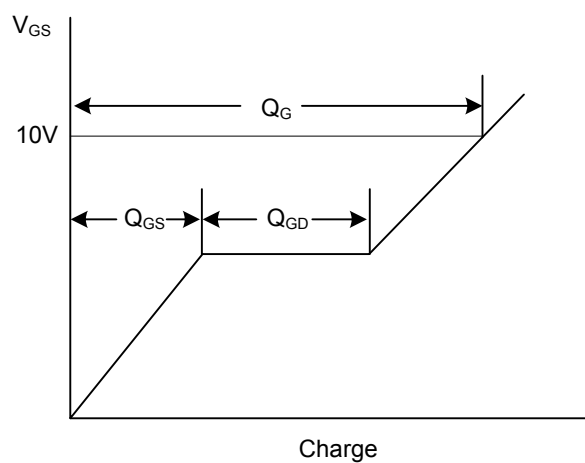
Switching Test Circuit



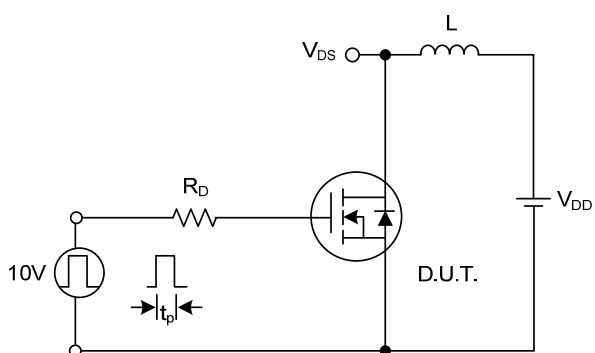
Switching Waveforms



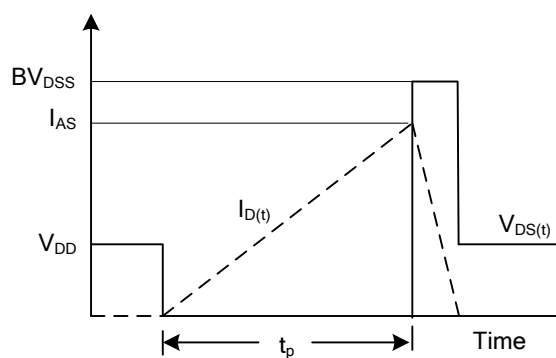
Gate Charge Test Circuit



Gate Charge Waveform

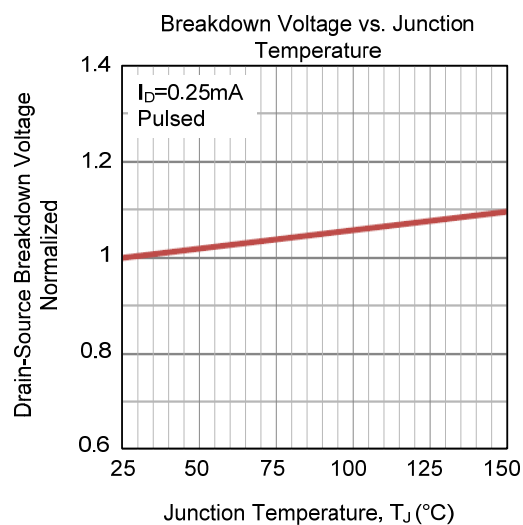
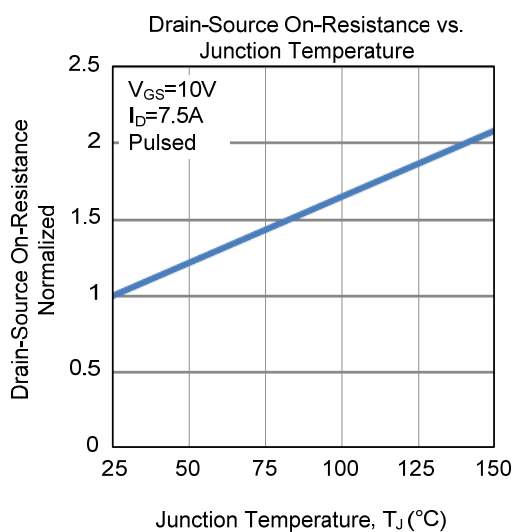
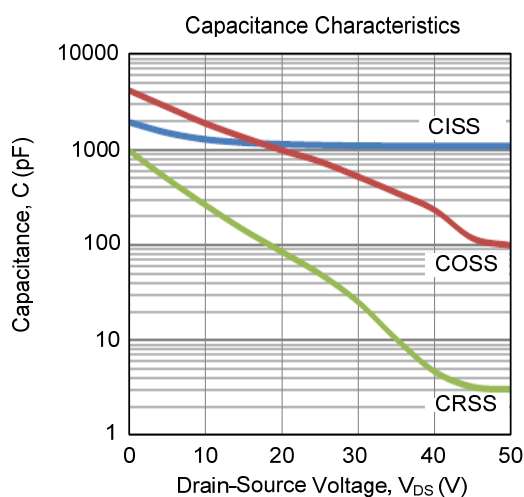
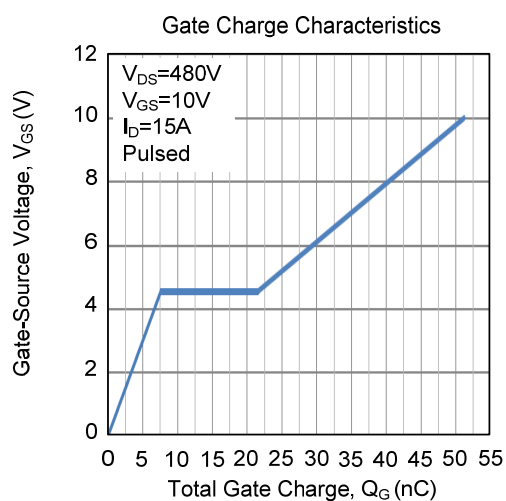
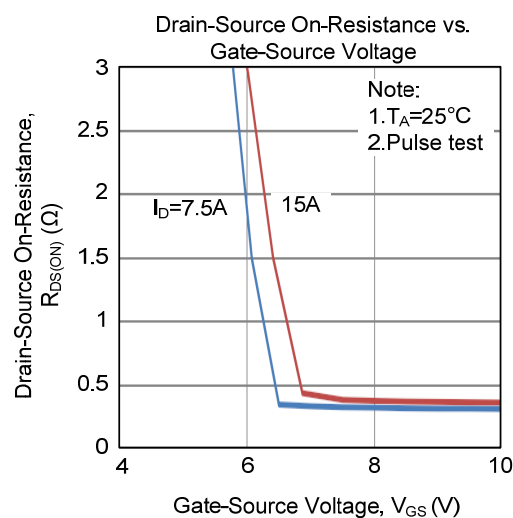
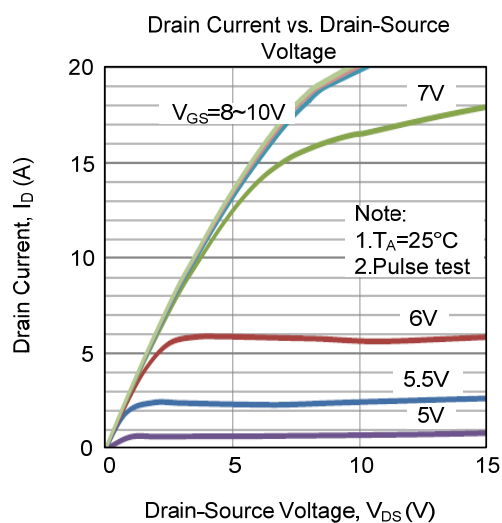


Unclamped Inductive Switching Test Circuit

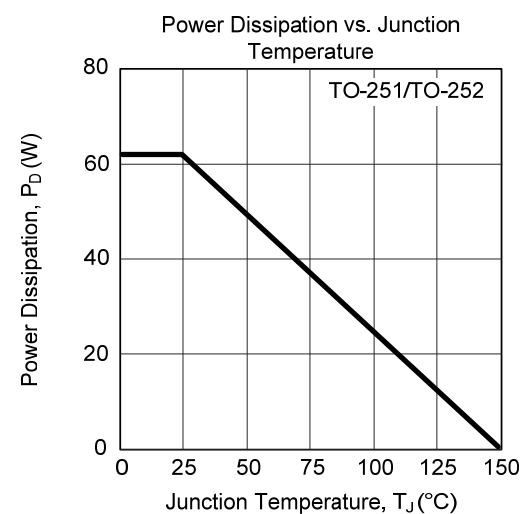
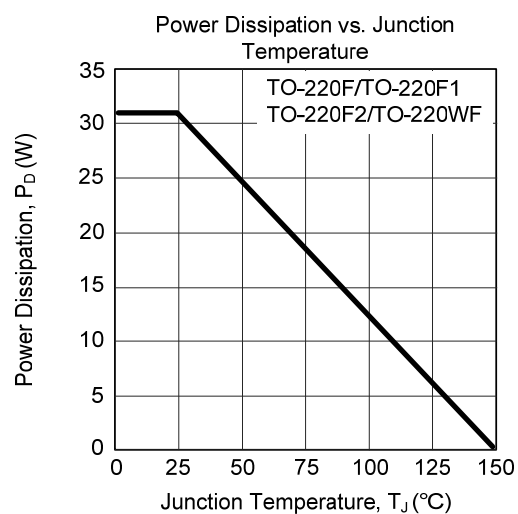
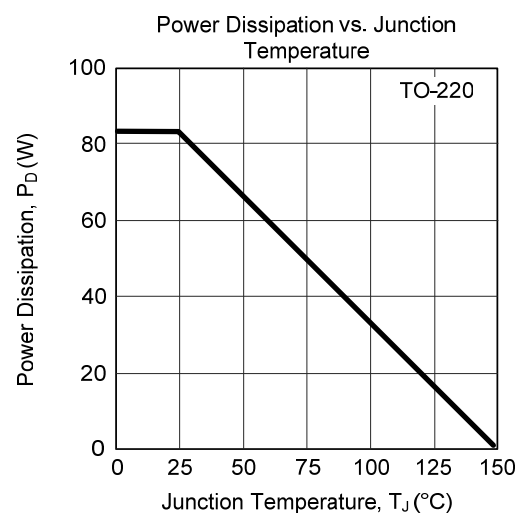
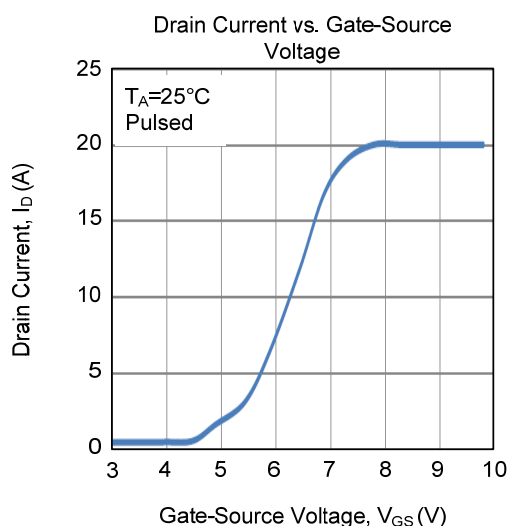
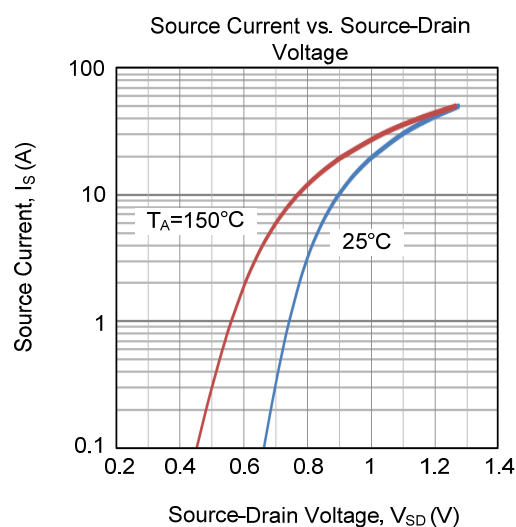
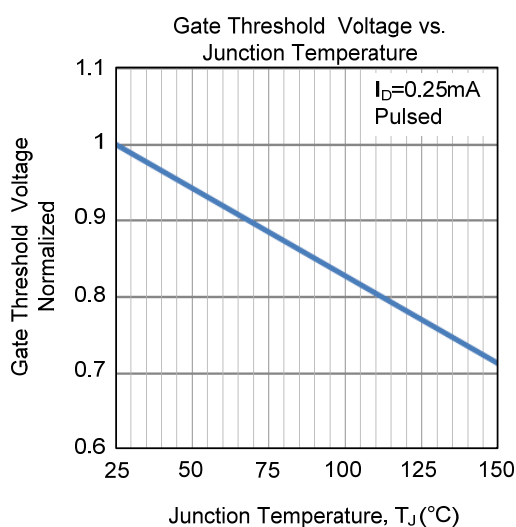


Unclamped Inductive Switching Waveforms

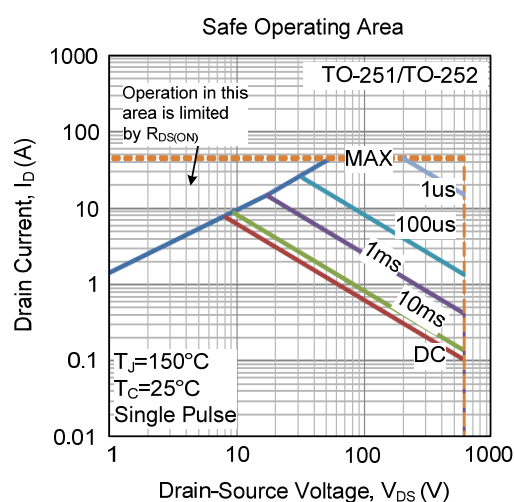
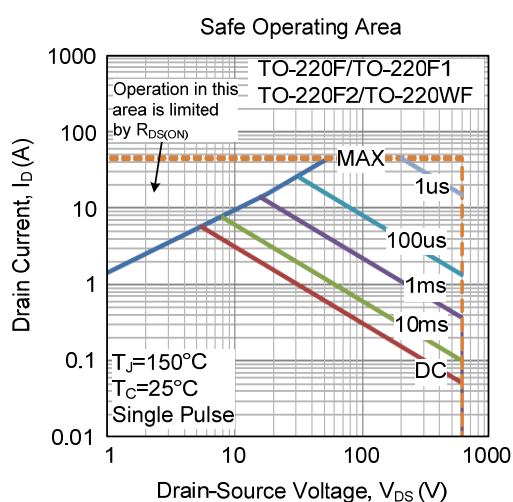
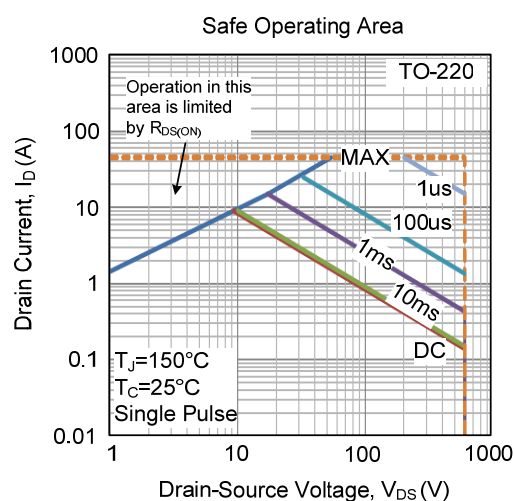
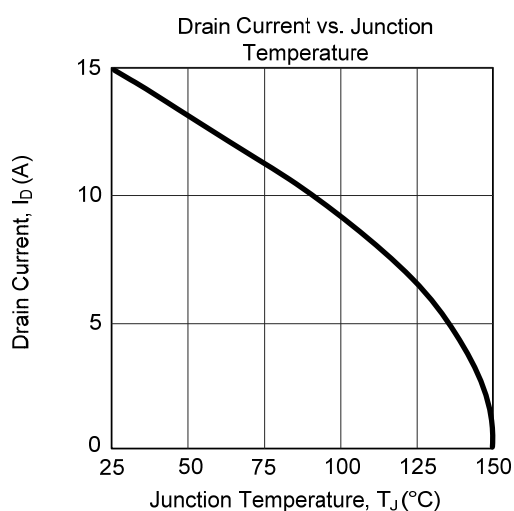
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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